

# PHOTO TRANSISTOR TYPE LED

## **Features**

- High intensity
- Wide viewing angle
- General purpose leads
- Reliable and rugged

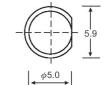
Absolute Maximum Ratings at Ta=25℃

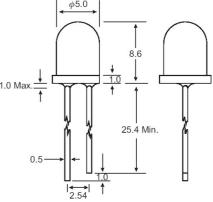
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Parameter	Symbol	Max.	Unit						
Power Dissipation	V <sub>BR(CEO)</sub>	100	mW						
Collector-Emitter Voltage	V <sub>BR(CEO)</sub>	30	V						
Emitter- Collector Voltage	V <sub>CE (SAT)</sub>	5	V						
Operating Temperature Range		-40°C to +80°C							
Storage Temperature Range		-40°C to +80°C							
Lead Soldering Temperature [4mm(.157") From Body]		260°C for 5 Seconds							

## Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.25mm (.010") unless otherwise noted.
- 3. Protruded resin under flange is 1.0mm (.04") max.
- 4. Lead spacing is measured where the leads emerge from the package.
- 5. Specifications are subject to change without notice.

## **Package Dimensions**





Unit: mm (inches)

Tolerance: ±0.25mm (.010") max

Part No.	Lens Color	Wavelength	•	Fall Time (90% to 10%) T <sub>F</sub> (µs)	Collector- Emitter Saturation Voltage	Collector Dark Current I <sub>D</sub> (nA)	On State Collector Current Ic(on)	Angular Response △ θ₁/2 (Deg)
		λp (nm)			Max	Max	Тур	Тур
EL-5PTWC	Water Clear	940	15	15	0.4	100	5.0	14
EL-5PTBD	Black Diffused	850	15	15	0.4	100	5.0	16

### **Parameter**

Collector-Emitter Breakdown Voltage Emitter-Collector Breakdown Voltage Collector-Emitter Saturation Voltage Collector Dark Current Rise Time & Fall Time On State Collector Current

### **Test Condition**

$$\begin{split} I_C &= 100 \mu A, \ I_B = 100 \mu A \\ I_E &= 100 \mu A, \ I_B = 100 \mu A \\ I_C &= 0.1 mA, \ H = 2.5 mW/cm^2 \\ V_{CE} &= 10V, \ H = 0 mW/cm^2 \\ V_{CE} &= 5V, \ I_C = 1 Ma, \ R_L = 100 \Omega \\ V_{CE} &= 5V, \ Ee = 1 mW/cm^2, \ \lambda = 940 nm \end{split}$$